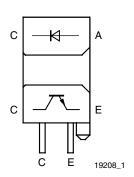


## **Transmissive Optical Sensor with Phototransistor Output**





#### **DESCRIPTION**

The TCST5250 is a transmissive sensor that includes an infrared emitter and a phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light.

#### **FEATURES**

· Package type: leaded

• Detector type: phototransistor

• Dimensions (L x W x H in mm): 14.3 x 6 x 9.5

• Gap (in mm): 2.7

• Aperture (in mm): 0.5

• Typical output current under test: I<sub>C</sub> = 1.5 mA

· Daylight blocking filter

• Emitter wavelength: 950 nm

• Lead (Pb)-free soldering released

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





### **APPLICATIONS**

- · Optical switch
- · Shaft encoder

PRODUCT SUMMARY					
PART NUMBER	GAP WIDTH (mm)	APERTURE WIDTH (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (1) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED	
TCST5250	2.7	0.5	1.5	Yes	

#### Note

(1) Conditions like in table basic characteristics/coupler

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
TCST5250	Tube	MOQ: 4860 pcs, 30 pcs/tube	-		

#### Note

(1) MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
COUPLER					
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	250	mW	
Ambient temperature range		T <sub>amb</sub>	- 25 to + 85	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	Distance to package 1.6 mm, t ≤ 5 s	T <sub>sd</sub>	260	°C	
INPUT (EMITTER)					
Reverse voltage		$V_{R}$	6	V	
Forward current		I <sub>F</sub>	60	mA	
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	3	Α	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	100	mW	
Junction temperature		Tj	100	°C	
OUTPUT (DETECTOR)					
Collector emitter voltage		V <sub>CEO</sub>	70	V	
Emitter collector voltage		V <sub>ECO</sub>	7	V	
Collector current		I <sub>C</sub>	100	mA	

# Transmissive Optical Sensor with Phototransistor Output



ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITION	ST CONDITION SYMBOL VALUE			
OUTPUT (DETECTOR)					
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub> 150		mW	
Junction temperature		Tj	100	°C	

#### Note

## **ABSOLUTE MAXIMUM RATINGS**

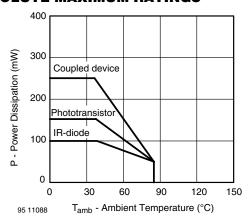


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (1)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
COUPLER	COUPLER						
Collector current	$V_{CE} = 10 \text{ V}, I_F = 20 \text{ mA}$	I <sub>C</sub>	0.5	1.5	15	mA	
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.2 \text{ mA}$	V <sub>CEsat</sub>			0.4	V	
INPUT (EMITTER)							
Forward voltage	I <sub>F</sub> = 60 mA	V <sub>F</sub>		1.25	1.5	V	
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C <sub>j</sub>		50		pF	
OUTPUT (DETECTOR)	OUTPUT (DETECTOR)						
Collector emitter voltage	I <sub>C</sub> = 1 mA	V <sub>CEO</sub>	70			V	
Emitter collector voltage	I <sub>E</sub> = 10 μA	V <sub>ECO</sub>	7			٧	
Collector dark current	$V_{CE} = 25 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I <sub>CEO</sub>		10	100	nA	
SWITCHING CHARACTERISTICS							
Turn-on time	$I_C = 1$ mA, $V_{CE} = 5$ V, $R_L = 100 \Omega$ (see figure 2)	t <sub>on</sub>		15		μs	
Turn-off time	$I_C = 1$ mA, $V_{CE} = 5$ V, $R_L = 100 \Omega$ (see figure 2)	t <sub>off</sub>		10		μs	

#### Note

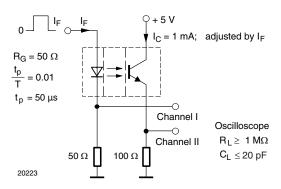
 $<sup>^{(1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified

 $<sup>^{(1)}</sup>$  T<sub>amb</sub> = 25 °C, unless otherwise specified



## Transmissive Optical Sensor with Phototransistor Output

## Vishay Semiconductors



## Fig. 2 - Test Circuit for $t_{\text{on}}$ and $t_{\text{off}}$

### T<sub>amb</sub> = 25 °C, unless otherwise specified

**BASIC CHARACTERISTICS** 

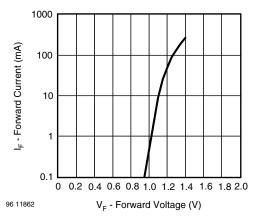


Fig. 4 - Forward Current vs. Forward Voltage

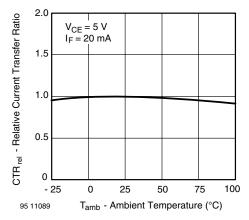


Fig. 5 - Relative Current Transfer Ratio vs. Ambient Temperature

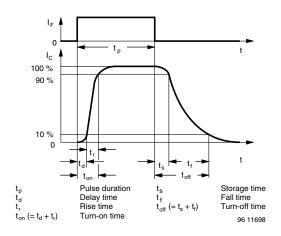


Fig. 3 - Switching Times

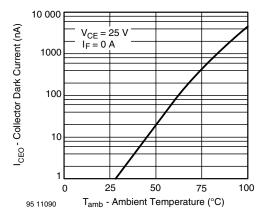


Fig. 6 - Collector Dark Current vs. Ambient Temperature

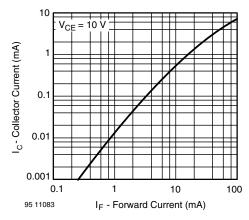


Fig. 7 - Collector Current vs. Forward Current

# Transmissive Optical Sensor with Phototransistor Output



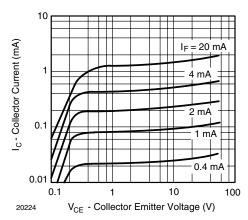


Fig. 8 - Collector Current vs. Collector Emitter Voltage

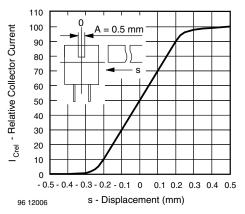


Fig. 11 - Relative Collector Current vs. Displacement

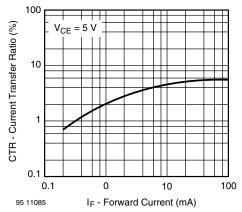


Fig. 9 - Current Transfer Ratio vs. Forward Current

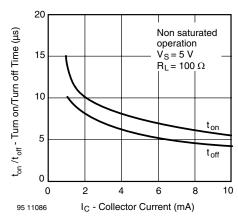


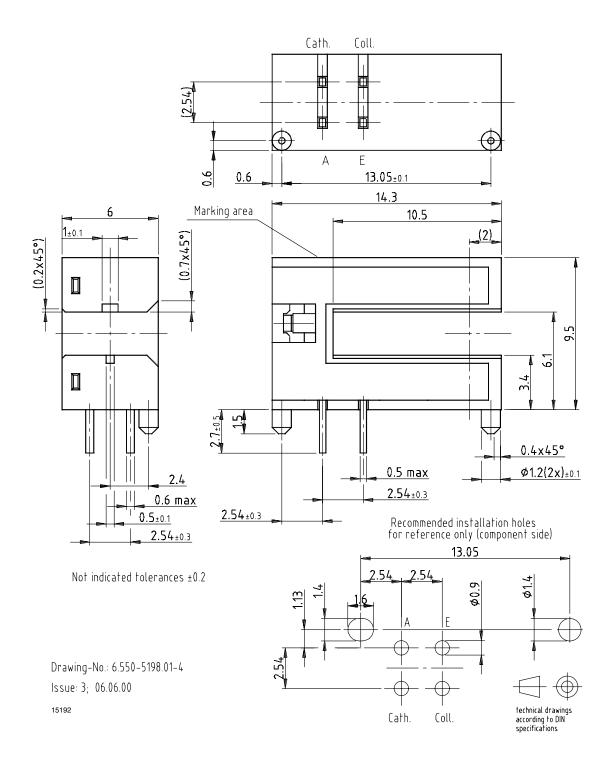
Fig. 10 - Turn-on/Turn-off Time vs. Collector Current



# Transmissive Optical Sensor with Phototransistor Output

# Vishay Semiconductors

### **PACKAGE DIMENSIONS** in millimeters

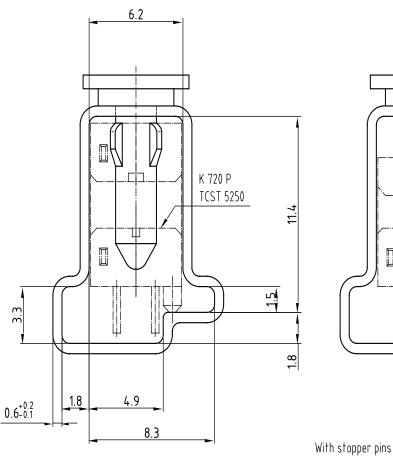


# Transmissive Optical Sensor with Phototransistor Output



K 721 P

### **TUBE DIMENSIONS** in millimeters



Tolerance: ±0.5mm Length: 450±1mm All dimensions in mm

Drawing-No.: 9.700-5222.01-4

Issue: 2; 19.11.04

20257



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